



香港中文大學

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3D Mixed-Size Placement with GPU Acceleration

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- ① Introduction
- ② 3D Mixed-Size Placement with GPU Acceleration
- ③ Experimental Results

Introduction

Cramming More Components onto Integrated Circuits



Moore's Law: The number of transistors on microchips doubles every two years

Moore's law describes the empirical regularity that the number of transistors on integrated circuits doubles approximately every two years. This advancement is important for other aspects of technological progress in computing – such as processing speed or the price of computers.

Our World
in Data

Transistor count

50,000,000,000

10,000,000,000

5,000,000,000

1,000,000,000

500,000,000

100,000,000

50,000,000

10,000,000

5,000,000

1,000,000

500,000

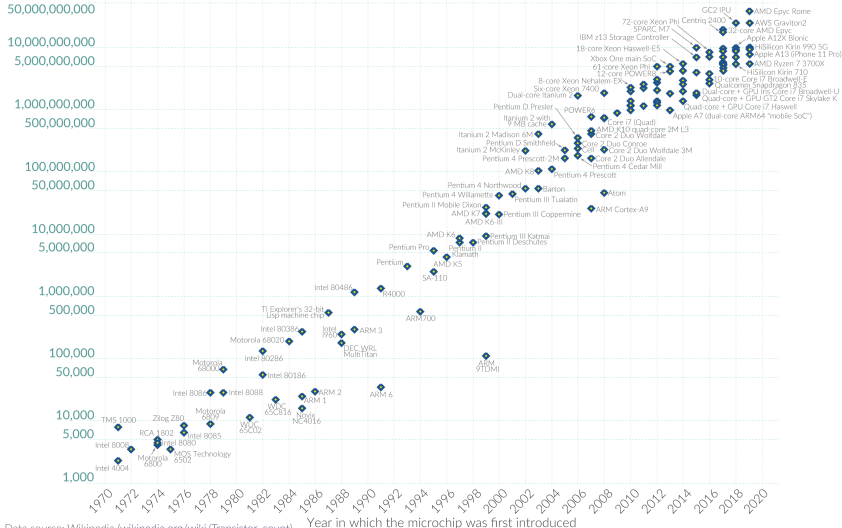
100,000

50,000

10,000

5,000

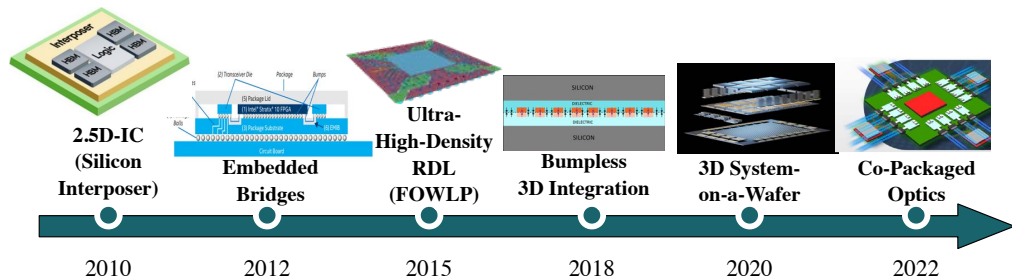
1,000



Data source: Wikipedia (wikipedia.org/wiki/Transistor_count)

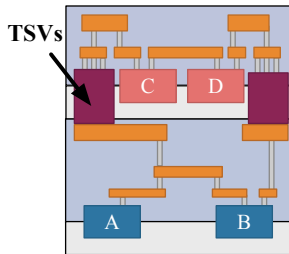
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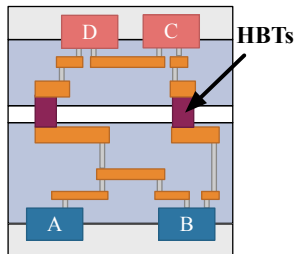
Source: Cadence

- Heterogeneous integration (HI) is a promising solution for better PPA, cost, and memory bandwidth.
- 3D integration is a key technology for HI to achieve Moore style gains.



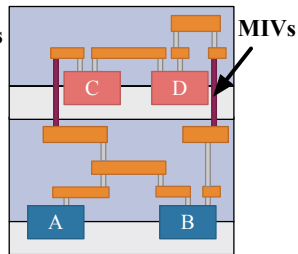
TSV based

- Commercially mature
- High area overhead
- High RC parasitics
- Pitch: $> 10 \mu\text{m}$



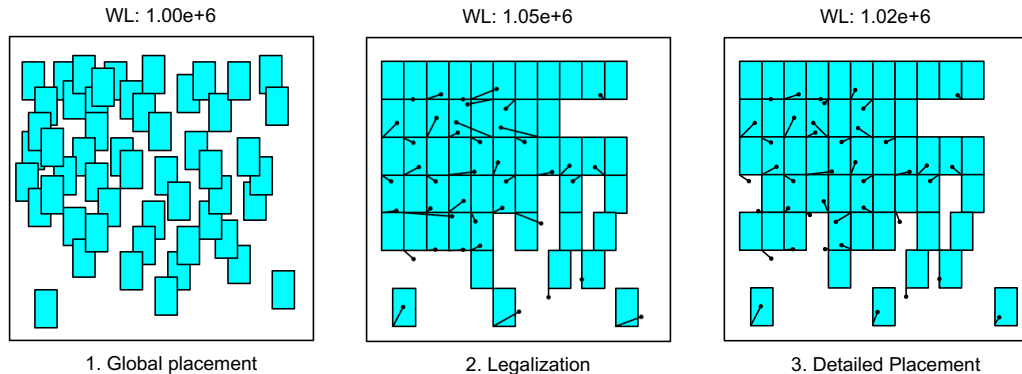
Hybrid bonding

- Low fabrication cost
- No area overhead
- Coupling issues
- Pitch: $1 \sim 10 \mu\text{m}$



Monolithic

- High fabrication cost
- High integration density
- Small RC parasitics
- Pitch: $\sim 0.1 \mu\text{m}$



- **Global placement:** Minimize the HPWL wirelength while satisfying the target density constraints.
- **Legalization:** Align cells to row and site without overlap.
- **Detailed placement:** Improve the objective based on the legal solution.



- **Pseudo-3D:** Pseudo-3D placers [TCAD'17]¹[ISPD'18]²[ICCAD23-Zhao]³ separate the partitioning and placement phases, and adopt 2D placement tools to determine instance locations.
- **True-3D:** True-3D placers relax the discrete tier partitioning and adopt analytical approaches [TCAD'13]⁴[TCAD'13]⁵[ISPD'16]⁶.

¹Shreepad Panth et al. (2017). “Shrunk-2-D: A physical design methodology to build commercial-quality monolithic 3-D ICs”. In: *IEEE TCAD* 36.10, pp. 1716–1724.

²Bon Woong Ku, Kyungwook Chang, and Sung Kyu Lim (2018). “Compact-2D: A physical design methodology to build commercial-quality face-to-face-bonded 3D ICs”. In: *Proc. ISPD*, pp. 90–97.

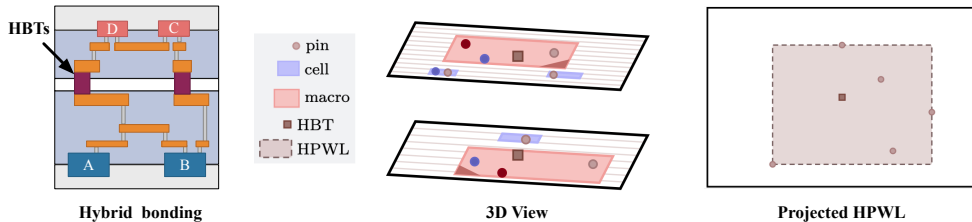
³Xueyan Zhao et al. (2023). “iPL-3D: A Novel Bilevel Programming Model for Die-to-Die Placement”. In: *Proc. ICCAD*.

⁴Guojie Luo, Yiyu Shi, and Jason Cong (2013). “An analytical placement framework for 3-D ICs and its extension on thermal awareness”. In: *IEEE TCAD* 32.4, pp. 510–523.

⁵Meng-Kai Hsu, Valeriy Balabanov, and Yao-Wen Chang (2013). “TSV-aware analytical placement for 3-D IC designs based on a novel weighted-average wirelength model”. In: *IEEE TCAD* 32.4, pp. 497–509.

⁶Jingwei Lu, Hao Zhuang, et al. (2016). “ePlace-3D: Electrostatics based placement for 3D-ICs”. In: *Proc. ISPD*, pp. 11–18.

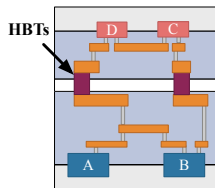
3D Mixed-Size Placement with GPU Acceleration



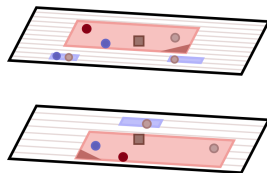
- All cells and macros on both dies should be placed at legal positions. Macros can be rotated with 0° , 90° , 180° , and 270° .
- For any crossing-die net, one hybrid bonding terminal (HBT) is inserted.
- Conventionally, the wirelength objective of a net e is the projected HPWL:

$$W_e(\mathbf{x}, \mathbf{y}) = p_e(\mathbf{x}) + p_e(\mathbf{y}), \quad p_e(\mathbf{x}) = \max_{i \in e} x_i - \min_{i \in e} x_i, \quad (1)$$

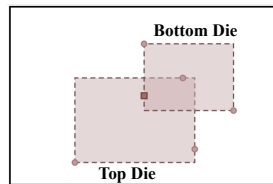
⁷Kai-Shun Hu et al. (2023). “2023 ICCAD CAD Contest Problem B: 3D placement with macros”. In: *Proc. ICCAD*. IEEE, pp. 1–6.



Hybrid bonding



3D View



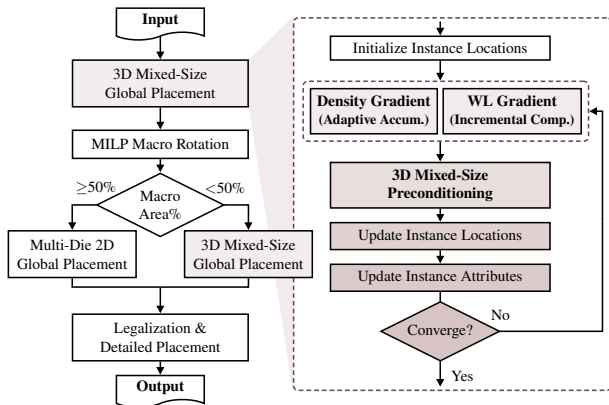
Die-to-Die HPWL

- **Die-to-Die HPWL:** the wirelength of a net e is the sum of the top net e^+ and bottom net e^- including the HBT,

$$W_e = W_{e^+} + W_{e^-}, \quad W_{e^+} = p_{e^+}(\mathbf{x}) + p_{e^+}(\mathbf{y}), \quad W_{e^-} = p_{e^-}(\mathbf{x}) + p_{e^-}(\mathbf{y}). \quad (1)$$

- **Heterogeneous** technology integration: instance layouts are different on different dies.

⁷Kai-Shun Hu et al. (2023). “2023 ICCAD CAD Contest Problem B: 3D placement with macros”. In: *Proc. ICCAD*. IEEE, pp. 1–6.



- 3D analytical formulation:

Constrained optimization

$$\begin{aligned} \min_{\mathbf{x}, \mathbf{y}, \mathbf{z}} \quad & \sum_{e \in E} W_e(\mathbf{x}, \mathbf{y}, \mathbf{z}) + \beta \sum_{e \in E} C_e, \\ \text{s.t.} \quad & D(\mathbf{x}, \mathbf{y}, \mathbf{z}) \leq t_d \end{aligned}$$

↓

Nonlinear analytical placement

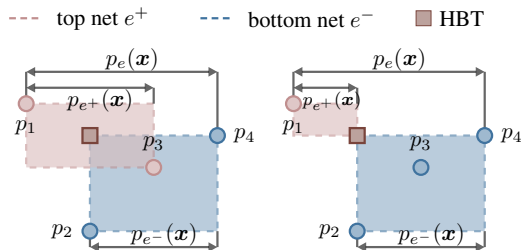
$$\min \underbrace{\sum_{e \in E} \hat{W}_e(\mathbf{x}, \mathbf{y}, \mathbf{z})}_{\text{Wirelength model}} + \lambda \underbrace{\hat{D}(\mathbf{x}, \mathbf{y}, \mathbf{z})}_{\text{Density model}}$$

- GPU-accelerated wirelength and density algorithms.

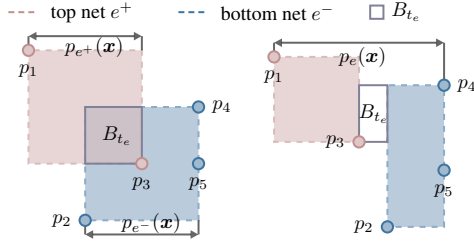
- Differentiable approximation of HPWL.
- The de facto choice: weighted-average model [TCAD'13],

$$W_e(\mathbf{x}) \approx \hat{W}_{e,WA}(\mathbf{x}) = \sum_{i=1}^n x_i \frac{e^{\frac{x_i}{\gamma}}}{\sum_{i=1}^n e^{\frac{x_i}{\gamma}}} - \sum_{i=1}^n x_i \frac{e^{-\frac{x_i}{\gamma}}}{\sum_{i=1}^n e^{-\frac{x_i}{\gamma}}}. \quad (2)$$

- The cut C_e can also be optimized by $\hat{W}_{e,WA}(\mathbf{z})$.



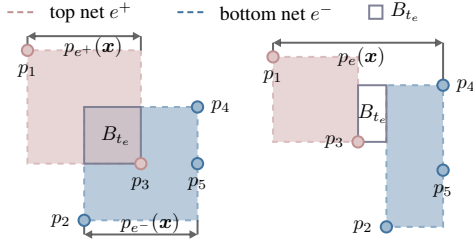
Applying WA to $p_e(\mathbf{x})$ is not always equivalent to $p_{e+}(\mathbf{x}) + p_{e-}(\mathbf{x})$.



- Where to place the HBT t_e for the crossing-die net e ?
- The optimal region $B_{t_e} = [x'_{\min}, x'_{\max}] \times [y'_{\min}, y'_{\max}]$ for the HBT t_e is defined as,

$$\begin{aligned} x'_{\min} &= \min \left\{ \max \left\{ x_{\min}^+, x_{\min}^- \right\}, \min \left\{ x_{\max}^+, x_{\max}^- \right\} \right\}, \\ x'_{\max} &= \max \left\{ \max \left\{ x_{\min}^+, x_{\min}^- \right\}, \min \left\{ x_{\max}^+, x_{\max}^- \right\} \right\}, \end{aligned} \quad (3)$$

⁹Peiyu Liao et al. (2023). “Analytical Die-to-Die 3D Placement with Bistratal Wirelength Model and GPU Acceleration”. In: *IEEE TCAD*.



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Bistratal Wirelength

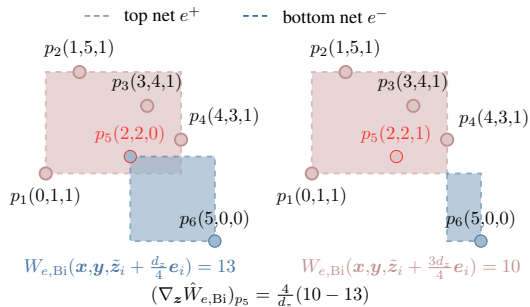
The partial nets e^+ and e^- are determined by the tentative partition $\delta = P(\mathbf{z})$.

$$W_{e,\text{Bi}}(\mathbf{x}, \mathbf{y}, \mathbf{z}) = \max \{p_e(\mathbf{x}), p_{e^+}(\mathbf{x}) + p_{e^-}(\mathbf{x})\} + \max \{p_e(\mathbf{y}), p_{e^+}(\mathbf{y}) + p_{e^-}(\mathbf{y})\}. \quad (4)$$

- Apply WA to $W_{e,\text{Bi}} \rightarrow \hat{W}_{e,\text{Bi}}$.

⁹Peiyu Liao et al. (2023). “Analytical Die-to-Die 3D Placement with Bistratal Wirelength Model and GPU Acceleration”. In: *IEEE TCAD*.

- How to optimize z by $\nabla_z \hat{W}_{e,Bi}$? (non-smooth)



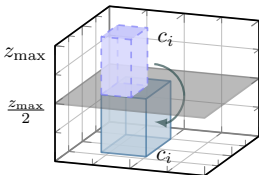
Finite Difference Approximation

The finite difference approximation (FDA) $(\nabla_z \hat{W}_{e,Bi})_i$ is defined by

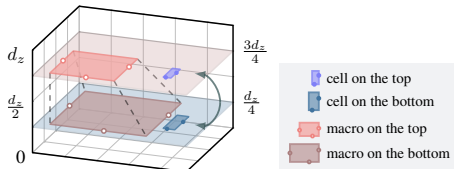
$$(\nabla_z \hat{W}_{e,Bi})_i = \frac{4}{d_z} \left(W_{e,Bi}(\mathbf{x}, \mathbf{y}, \tilde{\mathbf{z}}_i + \frac{3d_z}{4} \mathbf{e}_i) - W_{e,Bi}(\mathbf{x}, \mathbf{y}, \tilde{\mathbf{z}}_i + \frac{d_z}{4} \mathbf{e}_i) \right), \quad (5)$$

where $\mathbf{x}$ and $\mathbf{y}$ are fixed, and $\tilde{\mathbf{z}}_i = \mathbf{z} \odot (\mathbf{1} - \mathbf{e}_i)$ and $\mathbf{e}_i \in \mathbb{R}^{|V|}$ is the unit vector with the i -th entry being 1 and others being 0.

- **Electrostatics-Based Density Model.** We adopt the eDensity3D [ISPD'16] with dynamically updating instance size for different technologies.



(a)



(b)

- Let w_i^+ denote the instance width on the top die, and w_i^- on the bottom die. The dynamic width w_i can be derived as

$$w_i = \delta_i w_i^+ + (1 - \delta_i) w_i^-. \quad (6)$$

- For any macro $v_i \in V_M$, we propose to linearly transform macro width as

$$w_i = \left(\frac{2z_i}{d_z} - \frac{1}{2}\right) w_i^+ + \left(\frac{3}{2} - \frac{2z_i}{d_z}\right) w_i^-. \quad (7)$$



- eDensity3D computes the density gradient by solving the 3D Poisson's equation using spectral methods.

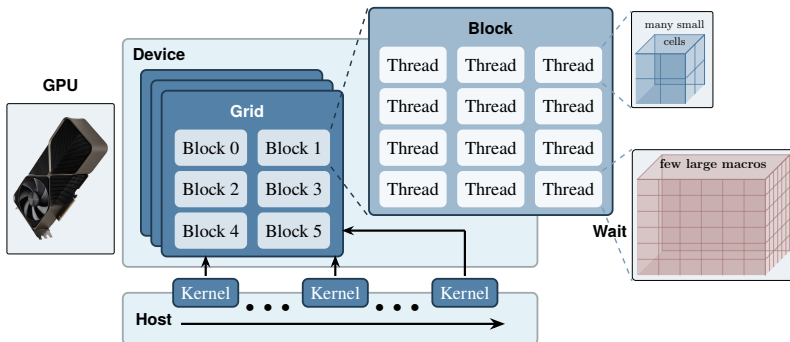
$$\begin{aligned}\Delta\phi(\mathbf{v}) &= -\rho(\mathbf{v}), & \mathbf{v} \in \Omega \\ \hat{\mathbf{n}} \cdot \nabla\phi(\mathbf{v}) &= 0, & \mathbf{v} \in \partial\Omega.\end{aligned}\tag{8}$$

- Let $(\omega_j, \omega_k, \omega_l) = (\frac{j\pi}{d_x}, \frac{k\pi}{d_y}, \frac{l\pi}{d_z})$ denote the frequency indices. The density frequency coefficients a_{jkl} are computed as

$$a_{jkl} = \frac{1}{N} \sum_{x,y,z} \rho(x,y,z) \cos(\omega_j x) \cos(\omega_k y) \cos(\omega_l z),\tag{9}$$

- The electric field $\mathbf{E}(x,y,z) = (E_x, E_y, E_z)$ is computed as below

$$\begin{aligned}E_x &= \sum_{j,k,l} \frac{a_{jkl}\omega_j}{\omega_j^2 + \omega_k^2 + \omega_l^2} \sin(\omega_j x) \cos(\omega_k y) \cos(\omega_l z), \\ E_y &= \sum_{j,k,l} \frac{a_{jkl}\omega_k}{\omega_j^2 + \omega_k^2 + \omega_l^2} \cos(\omega_j x) \sin(\omega_k y) \cos(\omega_l z), \\ E_z &= \sum_{j,k,l} \frac{a_{jkl}\omega_l}{\omega_j^2 + \omega_k^2 + \omega_l^2} \cos(\omega_j x) \cos(\omega_k y) \sin(\omega_l z).\end{aligned}\tag{10}$$

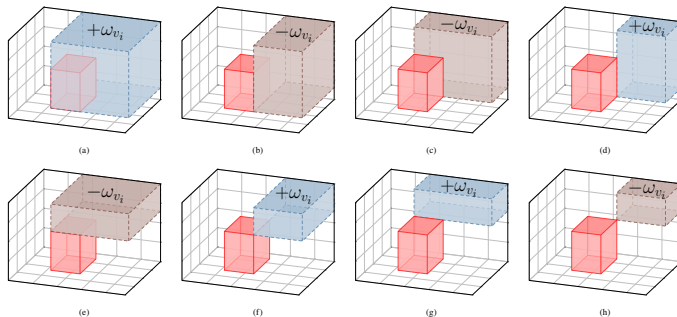


- For each bin $b \in B$ as a cuboid with size $w_b \times h_b \times d_b$, the density is calculated as,

$$\rho_b = \sum_{v_i \in V} \omega_{v_i} \frac{\text{vol}(D_{v_i} \cap b)}{\text{vol}(b)}, \quad (11)$$

where D_{v_i} indicates the region of the instance v_i in 3D space.

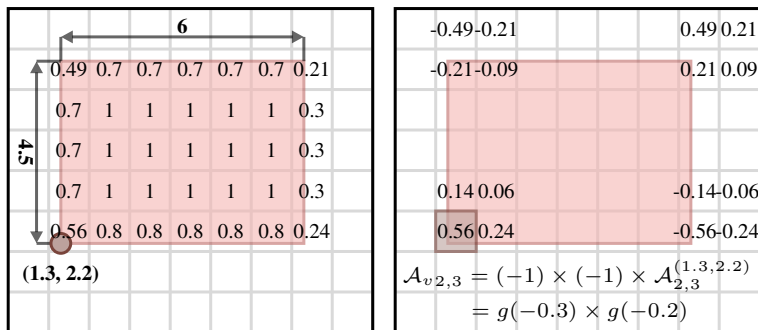
- The computation workload can be very imbalanced for standard cells and macros in 3D scenarios.



- The 3D density map calculation for macro v_i colored in **red** is decomposed to the weighted sum of 8 corner maps, performed by 3D prefix sum.
- The *3D prefix sum* is a function $\varphi : \mathbb{R}^{N_x \times N_y \times N_z} \rightarrow \mathbb{R}^{N_x \times N_y \times N_z}$ such that

$$\varphi(\mathcal{A})_{ijk} = \sum_{i'=1}^i \sum_{j'=1}^j \sum_{k'=1}^k \mathcal{A}_{i'j'k'} \quad (12)$$

holds for any 3D map $\mathcal{A} \in \mathbb{R}^{N_x \times N_y \times N_z}$ and valid index tuple (i, j, k) .



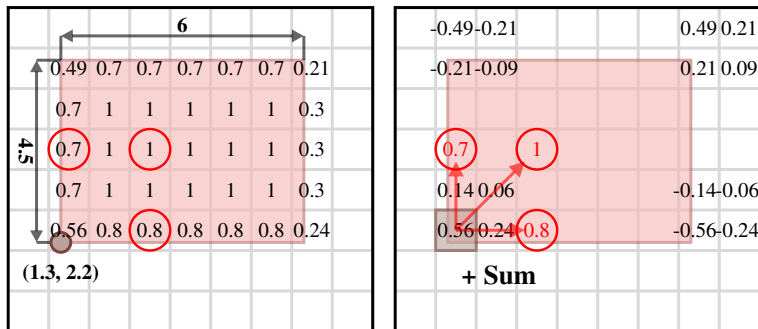
- Let a 3D map $\mathcal{A}^{(x,y,z)}$ be induced according to the following mechanism,

$$g(a) = \max\{1 - |a|, 0\}, \quad \mathcal{A}_{ijk}^{(x,y,z)} = g(i - 1 - \hat{x}) g(j - 1 - \hat{y}) g(k - 1 - \hat{z}), \quad (13)$$

where the normalized coordinates $(\hat{x}, \hat{y}, \hat{z}) := (\frac{x}{w_b}, \frac{y}{h_b}, \frac{z}{d_b})$.

- Then the desired 3D map $\mathcal{A}_{v_i}$ for macro v_i can be obtained by

$$\mathcal{A}_{v_i} = \sum_{\sigma_x, \sigma_y, \sigma_z \in \{-1, 1\}} -\sigma_x \sigma_y \sigma_z \mathcal{A}^{(x_i + \sigma_x \frac{w_i}{2}, y_i + \sigma_y \frac{h_i}{2}, z_i + \sigma_z \frac{d_i}{4})}. \quad (14)$$



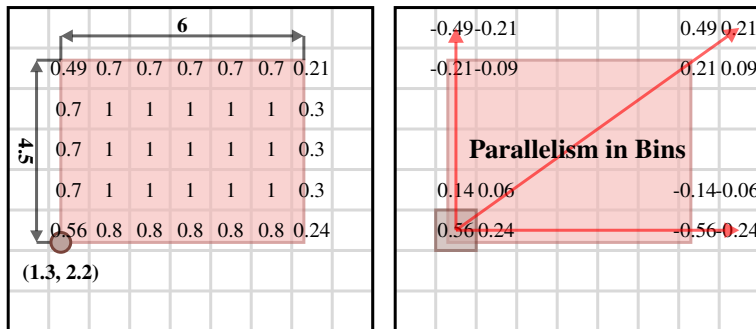
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- The eDensity families [TODAES'15]¹⁰ [ISPD'16] adopt the Jacobi preconditioner,

$$(\mathbf{H}_f)_{ii} = \sum_e \frac{\partial^2 \hat{W}_e}{\partial x_i^2} + \lambda \frac{\partial^2 \hat{D}}{\partial x_i^2}. \quad (15)$$

- We propose the 3D mixed-size preconditioner as follows,

$$(\mathbf{H}_f)_{ii} \approx \begin{cases} \max \{1, |E_i| + \lambda q_i\}, & \text{if } v_i \in V_M, \\ \max \{1, \lambda q_i\}, & \text{otherwise.} \end{cases} \quad (16)$$

¹⁰Jingwei Lu, Pengwen Chen, et al. (2015). “ePlace: Electrostatics-based placement using fast fourier transform and Nesterov’s method”. In: *ACM TODAES 20.2*, pp. 1–34.



- **Multi-Die 2D Placement:** We model the top die, bottom die, and bonding terminal layer as independent 2D electrostatic fields,

$$\min_{\mathbf{x}, \mathbf{y}} \sum_{e \in E} \hat{W}_e(\mathbf{x}, \mathbf{y}) + \langle \boldsymbol{\lambda}, \hat{\mathbf{D}} \rangle, \quad (17)$$

- **Legalization:** Die-by-die legalization by Tetris [US Patent'02]¹¹ and Abacus [ISPD'08]¹².
- **Detailed Placement:** Die-by-die detailed placement by ABCDPlace [TCAD'20]¹³.

¹¹Dwight Hill (2002). *Method and system for high speed detailed placement of cells within an integrated circuit design*. US Patent 6,370,673.

¹²Peter Spindler, Ulf Schlichtmann, and Frank M. Johannes (2008). “Abacus: fast legalization of standard cell circuits with minimal movement”. In: *Proc. ISPD*, pp. 47–53.

¹³Yibo Lin et al. (2020). “ABCDPlace: Accelerated batch-based concurrent detailed placement on multithreaded CPUs and GPUs”. In: *IEEE TCAD* 39.12, pp. 5083–5096.

Experimental Results

- **Benchmarks:** 3D mixed-size placement benchmarks from ICCAD 2023 contest.
- **Metrics:** Wirelength, HBT count, and runtime. The raw score = $\text{HPWL} + \beta \# \text{HBTs}$ ($\beta = 10$).
- **Platform:** Intel Xeon Silver 4210R CPU (2.40GHz), 1 GeForce RTX 3090Ti GPU.

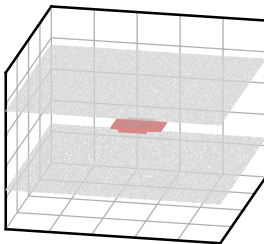
Table: The statistics of ICCAD 2023 contest benchmarks [ICCAD'23].

Bench.	#Cells	#Macros	#Nets	RH ⁺	RH ⁻	w'	r _{MA}
case2	13901	6	19547	33	33	92	0.88
case2h1	13901	6	19547	33	48	92	0.88
case2h2	13901	6	19547	33	48	92	0.88
case3	124231	34	164429	33	48	56	0.71
case3h	124231	34	164429	36	48	58	0.67
case4	740211	32	758860	92	115	54	0.36
case4h	740211	32	758860	55	69	32	0.36

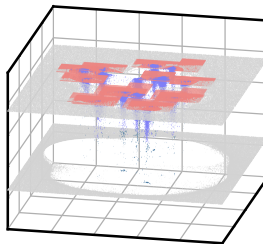
Table: Placement results compared to the top-3 winners on the ICCAD 2023 contest benchmark.

Bench.	1st Place			2nd Place			3rd Place			Ours-CPU			Ours-GPU		
	HPWL	#HBTs	RT	HPWL	#HBTs	RT	HPWL	#HBTs	RT	HPWL	#HBTs	RT	HPWL	#HBTs	RT
case2	16 490 836	1523	67	16 277 152	993	32	16 537 596	2153	144	15528810	1128	76	15 622 062	1329	38
case2h1	18 121 844	120	39	19 047 767	821	43	21 156 596	2435	160	16 708 363	1135	80	16556213	1349	35
case2h2	18 123 283	120	42	19 193 899	821	41	21 640 714	2426	162	16748148	1091	80	16 807 840	1312	36
case3	98 706 330	22 189	534	105 386 847	26 112	104	116 022 515	29 457	602	97281904	10 704	236	98 081 778	12 446	92
case3h	122 271 798	18 761	262	120 770 382	5038	104	117 633 295	25 641	612	109 386 719	13 224	239	108028790	13 798	86
case4	1 046 106 185	160 993	3605	1 108 969 124	188 137	615	1 130 211 865	138 762	5309	1 040 202 500	132 109	3070	1036364973	131 119	335
case4h	654 962 287	156 586	1567	680 554 407	167 686	592	702 244 786	141 916	4492	634 654 510	133 734	2640	633920946	133 853	361
Average	1.058	0.981	4.000	1.096	1.019	1.289	1.156	1.660	7.830	1.000	0.907	4.047	1.000	1.000	1.000

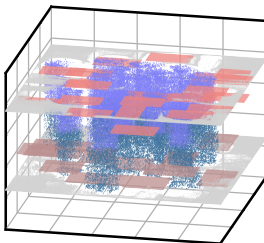
- **5.8%** HPWL improvement with similar #HBTs compared to the 1st place.
- **4.0×** runtime speedup compared to the 1st place by GPU acceleration.



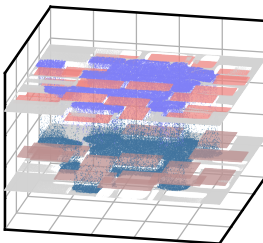
Iter.	WL (10^7)	#HBTs	OVFL
0	3.60	88507	1.00



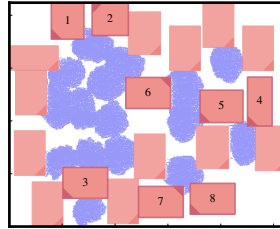
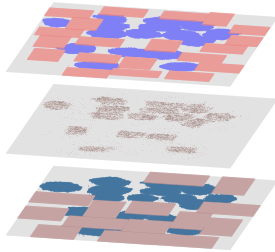
Iter.	WL (10^7)	#HBTs	OVFL
1000	4.49	1254	0.89



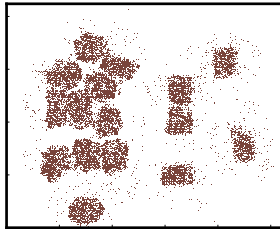
Iter.	WL (10^7)	#HBTs	OVFL
1800	10.30	30961	0.34



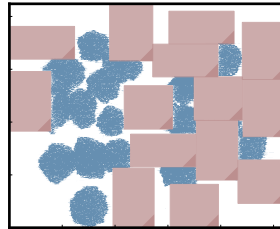
Iter.	WL (10^7)	#HBTs	OVFL
2142	10.51	13798	0.07



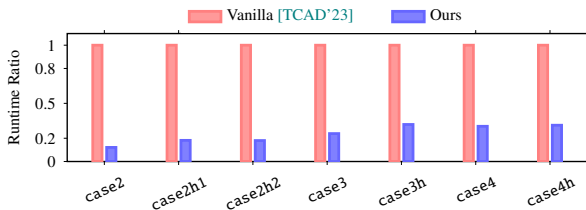
top die



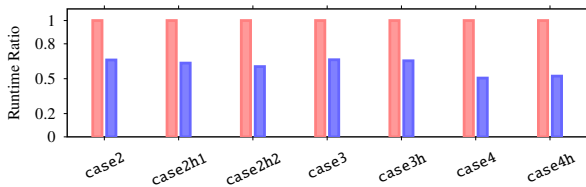
HBTs



bottom die

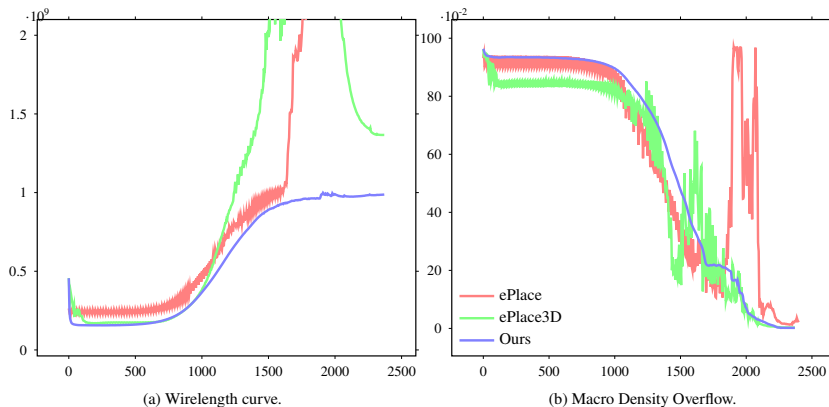


(a) Density algorithm runtime comparison.



(b) Wirelength algorithm runtime comparison.

- $4.7\times$ speedup by adaptive 3D density accumulation.
- $1.7\times$ speedup by incremental wirelength gradient algorithm.



Ablation study on the mixed-size preconditioner.

- Our mixed-size preconditioner enables stable optimization.

Q&A